NSN 5961-01-375-3621



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-375-3621 **Inclosure Material:** Metal and glass **Overall Length:** Between 0.790 inches and 0.800 inches **Terminal Length:** Between 0.530 inches and 0.550 inches **Overall Height:** Between 0.249 inches and 0.260 inches **Overall Width:** Between 0.535 inches and 0.545 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-254aa **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -20.0 gate to source voltage and 20.0 gate to source voltage and 500.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 12.00 amperes drain current and 48.00 amperes off-state current, peak and 12.00 amperes source current **Power Rating Per Characteristic:** 150.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:**

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/592 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0